

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Tc = +25°С
60V	10mΩ @ Vgs = 10V	89.5A
000	$12m\Omega @ V_{GS} = 4.5V$	81.7A

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. The device is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- High-Frequency switching
- Synchronous rectifications
- DC-DC converters

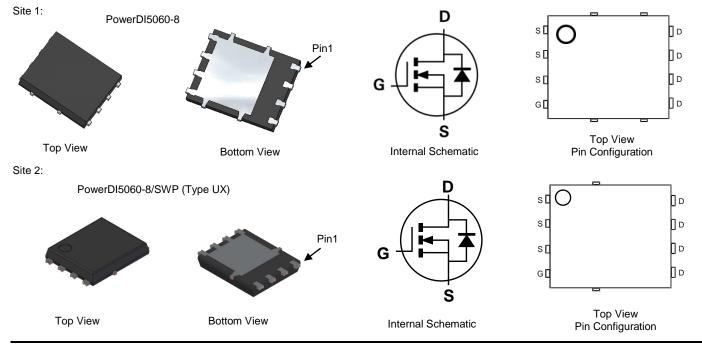
#### **Features**

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub>—Minimizes Power Losses
- Low Q<sub>G</sub>—Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6009LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish—Matte Tin Annealed over Copper Leadframe, Solderable per MIL-STD-202, Method 208
- Weight: 0.097 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMTH6009LPSQ-13	PowerDI5060-8	2500	Tape & Reel	
DMTH6009LPSQ-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

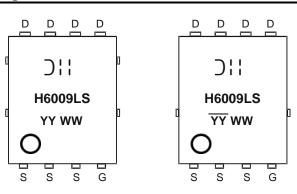
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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# **Marking Information**



) | | = Manufacturer's Code Marking H6009LS = Product Type Marking Code YYWW = Date Code Marking YY or  $\overrightarrow{YY}$  = Year (ex: 23 = 2023) WW = Week (01 to 53)

**Maximum Ratings**  $(@T_A = +25^{\circ}C, unless otherwise specified.)$ 

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	60	V	
Gate-Source Voltage		Vgss	±16	V
Continuous Drain Current (Note 5)	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	ID	11.76 8.3	А
Continuous Drain Current (Note 6)	Tc = +25°C Tc = +100°C	ID	89.5 63.3	A
Maximum Continuous Body Diode Forward Current (Note 6)		ls	89	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	350	A
Pulsed Body Diode Forward Current (380µs Pulse, Duty Cycle = 1%)		Isм	350	А
Avalanche Current, L = 0.1mH		las	20.3	А
Avalanche Energy, L = 0.1mH		Eas	20.6	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	53	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	136	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).



## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

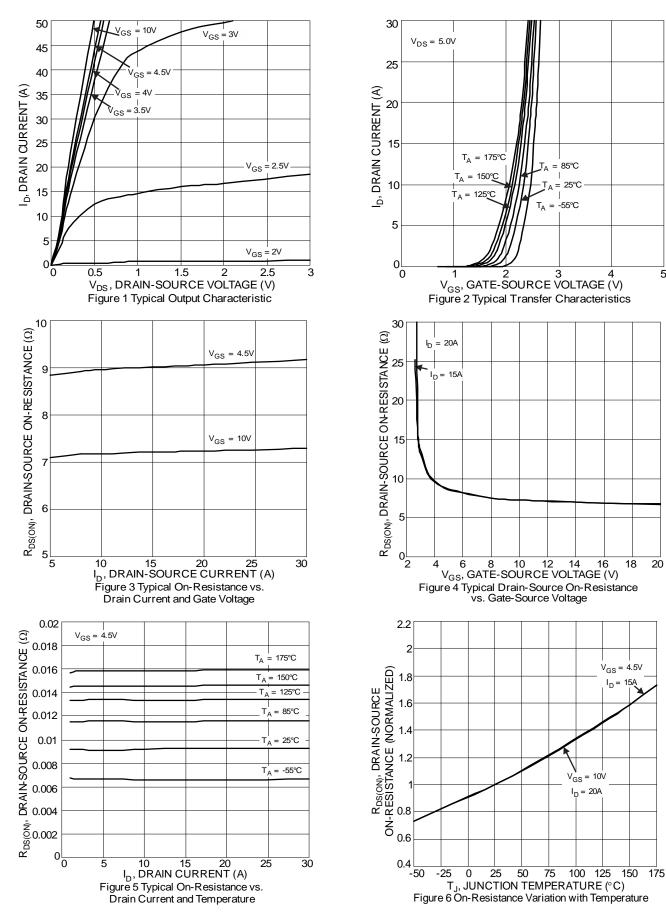
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)		0				1
Drain-Source Breakdown Voltage	BVDSS	60	—	—	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.7	—	2	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Deserve	_	7.2	10	mΩ	VGS = 10V, ID = 20A
Static Drain-Source On-Resistance	RDS(ON)	—	8.9	12	11152	$V_{GS} = 4.5V, I_D = 15A$
Diode Forward Voltage	Vsd	—	0.9	1.2	V	VGS = 0V, IS = 20A
DYNAMIC CHARACTERISTICS (Note 8)						·
Input Capacitance	Ciss	—	1,925	—		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz
Output Capacitance	Coss	—	438	—	pF	
Reverse Transfer Capacitance	Crss	—	41	—		
Gate Resistance	Rg	—	1.7	—	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	33.5	—		
Total Gate Charge ( $V_{GS} = 4.5V$ )	Qg	_	15.6	_	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 13.5A
Gate-Source Charge	Qgs	—	4.7	—	nc	
Gate-Drain Charge	Qgd	_	5.3			
Turn-On Delay Time	tD(ON)	—	4.5	—		
Turn-On Rise Time	t <sub>R</sub>	_	8.6			$\label{eq:VDD} \begin{array}{l} V_{DD} = 30V, \ V_{GS} = 10V, \\ R_{G} = 6\Omega, \ I_{D} = 13.5A \end{array}$
Turn-Off Delay Time	tD(OFF)		35.9	—	ns	
Turn-Off Fall Time	tF	_	15.7	—		
Body Diode Reverse Recovery Time	trr		18.2		ns	
Body Diode Reverse Recovery Charge	Qrr	_	33.1	—	nC	I <sub>F</sub> = 13.5A, di/dt = 400A/µs

Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.



# DMTH6009LPSQ

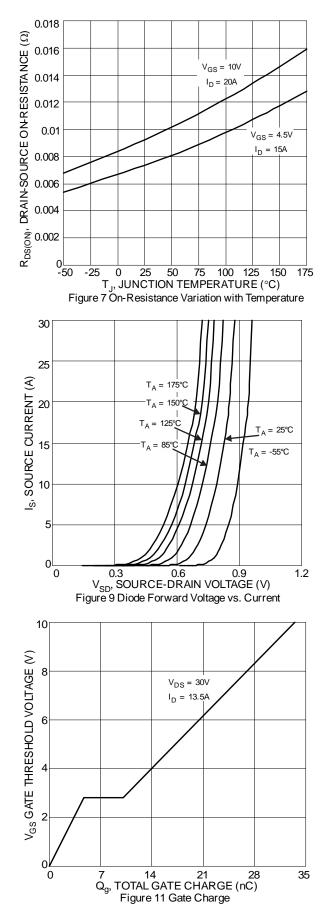
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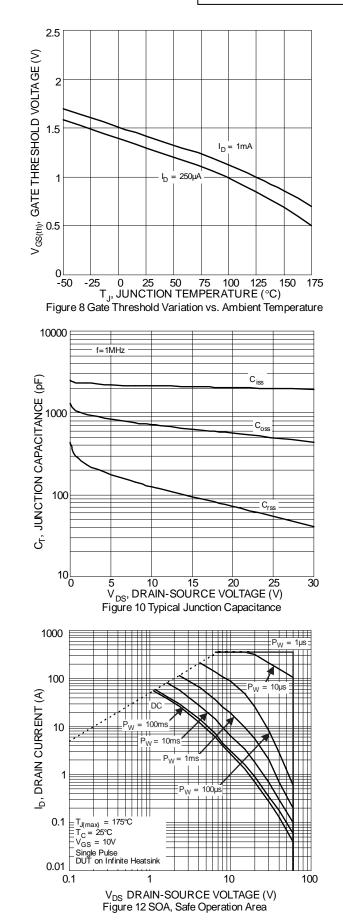


DMTH6009LPSQ Document number: DS40885 Rev.3 - 2

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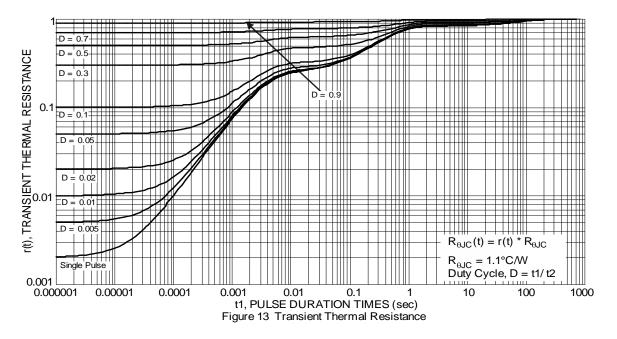






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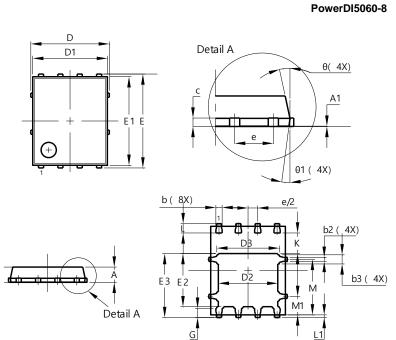




# **Package Outline Dimensions**

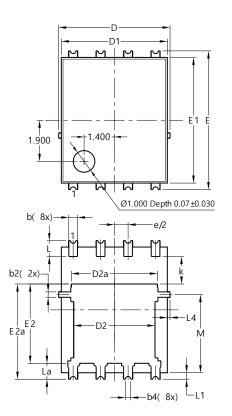
Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

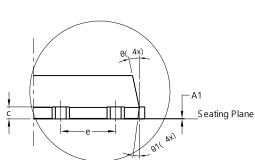


	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	(	6.15 BSC			
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
Al	All Dimensions in mm				

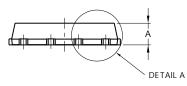
Site 2:



PowerDI5060-8/SWP (Type UX)



DETAIL A



PowerDI5060-8/SWP (Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	(	).25REF		
С	0.230	0.330	0.277	
D	5	.15 BS0	0	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
E	6	6.40 BSC		
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a		4.595		
е	1	.27BSC	)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0	.050RE		
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	All Dimensions in mm			

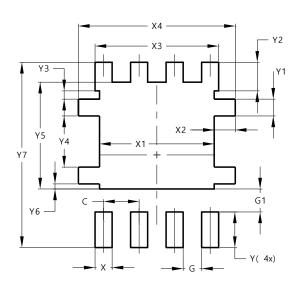


## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

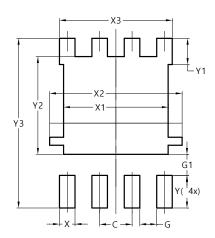
#### PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

#### PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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